

A product Line of Diodes Incorporated



PI90LV01/PI90LVB01

SOTiny LVDS High-Speed Differential Line Driver

Features

- → Meets or Exceeds ANSI TIA/EIA-644-1955 Standard
- → Signaling rates up to 660 Mbps
- → Bus-Terminal ESD exceeds 2kV
- → Low-Voltage Differential Signaling with typical Output Voltages of 350mV:
 - 100-ohm load (PI90LV01)
 - 50-ohm load (PI90LVB01)
- → Typical Propagation Delay Times of 1.5ns
- → Typical Power Dissipation of 20mW @200 MHz
- → Low-Voltage TTL (LVTTL) Level is 5V Tolerant
- → Operates from a 3.3V supply
- → Extended Industrial Temperature Operating Range: -40°C to 105°C
- → Packaging (Pb-free & Green available):
 - 5-pin space-saving SOT23 (T)

Vcc

GND

7

Description

The PI90LV01 and PI90LVB01 are differential line drivers that use low-voltage differential signaling (LVDS) to support data rates up to 660 Mbps. These products are designed for applications requiring high-speed, low-power consumption, low-noise generation, and a small package.

The TIA/EIA-644 standard compliant electrical interface provides a minimum differential output voltage magnitude of 247mV into a 100- ohm load and receipt of 100mV signals with up to 1V of ground potential difference between a transmitter and receiver. The PI90LVB01 doubles the output drive current to achieve LVDS levels with a 50-ohm load.

A low-voltage TTL/CMOS input level is translated by the device into a low-voltage (350mV) differential output signal.

Applications

Applications include point-to-point (single termination) and multi-point (double termination) baseband data transmissions over controlled impedance media . The transmission media can be printed circuit board traces, backplanes, or cables.

The PI90LV01 and companion line receivers (PI90LV02 and PI90LVT02) provide new alternatives to RS-232, PECL and ECL devices for high-speed, point-to-point interface applications.

Logic Diagram



Function Table

Pinout

| Inputs | Outputs | | |
|-----------------|---------|---|--|
| D _{IN} | Y | Z | |
| Н | Н | L | |
| L | L | Н | |
| Open | L | Н | |

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4

] DIN

1

2

3

Notes:

- H = HighL = Low
- L = LowX = High or Lo
- X = High or Low High Z = High Impedance

PI90LV01-PI90LVB01 Document Number DS40163 Rev 1-2





Absolute Maximum Ratings

(Over Operating Free-Air Temperature, unless otherwise noted)[†]

| Supply Voltage Range, VCC(1)0.5V to 4V |
|---|
| Input Voltage Range (DIN)–0.5 to 6V |
| (Y or Z)0.5 to 4V |
| ESD Rating (HBM, 1.5K-Ohms, 100pF) $\geq 2 \mathrm{KV}$ |
| Continuous total power dissipation See dissipation rating table |
| Storage Temperature Range65°C to 150°C |
| Lead Temperature 1.6 mm (1/16 inch) from case for 10 seconds 250 $^{\circ}\mathrm{C}$ |
| |

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

1. All voltage values, except differential I/O bus voltages, are with respect to ground terminal.

Dissipation Rating Table

| Package | $T_A \le 25^{\circ}C$ Power Rating | Derating Factor Above $T_A = 25^{\circ}C^{*}$ | T _A = 85°C Power Rating | |
|---------|------------------------------------|---|------------------------------------|--|
| Т | 385mW | 3.1mW/°C | 200mW | |

^{*}This is the inverse of the junction-to-ambient thermal resistance when board-mounted (low-K) and with no air flow.

Recommended Operating Conditions

| | Min. | Nom. | Max. | Units |
|--|------|------|------|-------|
| Supply Voltage, V _{CC} | 3.0 | 3.3 | 3.6 | |
| High-Level Input Voltage, V _{IH} | 2 | | 3.8 | V |
| Low-Level Input Voltage, V _{IL} | | | 0.8 | |
| Operating free-air temperature, T _A | -40 | | 105 | °C |





| Symbol | Parameter | Test Conditions | | Min. | Typ. ⁽¹⁾ | Max. | Units |
|---------------------|---|--|-----|-------|----------------------------|-------|-------|
| V _{OD} | Differential output voltage magnitude | $R_{L} = 100 \text{ ohms ('LV01)}$ $R_{L} = 50 \text{ ohms ('LVB01)}$ See Figure 1 | | 247 | 350 | 454 | mV |
| $\Delta V_{OD} $ | Change in differential output voltage magnitude between logic states | | | -50 | | 50 | mv |
| V _{OC(SS)} | Steady-state common-mode output voltage | See Figure 2 | | 1.125 | | 1.375 | V |
| $\Delta V_{OC(SS)}$ | Change in steady-state common- mode output voltage between logic states | | | -50 | | 50 | mV |
| V _{OC(PP)} | Peak-to-peak common-mode output voltage | | | | 25 | 100 | |
| | I _{cc} Supply current | $V_{I} = 0V$ or V_{CC} , No Load | | | 2 | 5.5 | |
| Icc | | $V_1 = 0V \text{ or } V_{CC}, R_L = 100 \text{ ohms ('LV01)}$ | | | 5.5 | 8 | mA |
| | | $V_{I} = 0V \text{ or } V_{CC}, R_{L} = 50 \text{ ohms ('LVB01)}$ | | | 7.0 | 14 | |
| IIH | High-level input current | $V_{IH} = 5V$ | | | 2 | 20 | |
| I _{IL} | Low-level input current | V _{IL} = 0.8V | | | 2 | 10 | μΑ |
| | | V_{ODOUT+} or $V_{ODOUT-} = 0V$ | LV | | 3 | 10 | mA |
| I _{os} Sho | Short-circuit output current | | LVB | | 6 | 20 | |
| | | $V_{OD} = 0V$ LV | LV | | | 10 | |
| | | | LVB | | | 20 | |
| I _{O(OFF)} | Power-off output current | $V_{\rm CC} = 0V, V_{\rm O} = 3.6V$ | | | | ±1 | μA |
| C _{IN} | Input capacitance | | | | 3 | | pF |

Electrical Characteristics (Over Operating Free-Air Temperature, unless otherwise noted)

Note:

1. All typical values are at 25°C and with a 3.3V

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| Symbol | Parameter | Test Conditions | Min | Typ. ⁽¹⁾ | Max. | Units |
|--------------------|---|--|-----|---------------------|------|-------|
| t _{PLH} | Propagation delay time, low-to-high level output | PI90LV01, $R_L = 100$ -ohms, $C_L = 10pF$ PI90LVB01, $R_L = 50$ -ohms, $C_L = 10pF$ See Figure 3 | | 1.5 | 2.7 | ns |
| t _{PHL} | Propogation delay time, high-to-low level output | | | 1.8 | 2.7 | |
| | Transition, low-to-high (PI90LV01) 0.6 | 0.6 | 1.5 | | | |
| t _r | Transition, low-to-high (PI90LBV01) | | | 0.5 | 1.4 | |
| t _f | Transition, high-to-low (PI90LV01) | | | 0.7 | 1.5 | |
| | Transition, high-to-low (PI90LBV01) | | | 0.6 | 1.4 | |
| t _{sk(p)} | Pulse skew $(t_{PHL} - t_{PLH})^{(2)}$ | | | 0.3 | - | |

Switching Characteristics, $V_{cc} = 3V$ to 3.6V (Over Operating Free-Air Temperature, unless otherwise noted)

Notes:

1. All typical values are at 25°C and with a 3.3V supply

2. tsk(p) is the magnitude of the time difference between the high-to-low and low-to-high propagation delay times at an output

3. f_{max} generator input conditions: 50% duty cycle, 0V to 3V. Output criteria: 45% to 55% duty cycle, $V_{OD} = 250 \text{mV}$





Parameter Measurement Information



Figure 1. Driver Voltage and Current Definitions



Note:

1. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, Pulse Repetition Rate

- (PRR) = 0.5 Mpps, Pulse width = 500 ±10ns. C_L includes instrumentation and fixture capacitance within 0.06mm of the D.U.T. The measurement of V_{OC(PP)} is made on test equipment with a -3dB bandwidth of at least 300MHz.
- 2. $R_1 = 49.9$ ohms ±1% for PI90LV01 or 24.9 ohms ±1% for PI90LVB01.





Parameter Measurement Information



Figure 3. Test Circuit, Timing, & Voltage Definitions for the Differential Output Signal







Figure 4.

Figure 5.



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PI90LV01/PI90LVB01

Packaging Mechanical: 5-Pin SOT23 (T)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

| Ordering Number | Package Code | Package Description | Top Marking | |
|-----------------|--------------|---|-------------|--|
| PI90LV01TEX | Т | 5-Pin, Small Outline Transistor Plastic Package (SOT23) | Ī.1 | |
| PI90LVB01TEX | Т | 5-Pin, Small Outline Transistor Plastic Package (SOT23) | L2 | |

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Notes:

Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/

• E = Pb-free and Green

• X suffix = Tape/Reel





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